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Body Length: 0.540 inches **Body Width:** 0.300 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 1.1 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and programmable and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** F-9 mil-m-38510 **Current Rating Per Characteristic:** 12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.0 volts power source Memory Device Type: Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 flat leads Shelf Life: N/a Unit Of Measure: **Demilitarization:** Yes - demil/mli

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